Diode Semiconductor Device - Page 1 of 1



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View Online at https://aerobasegroup.com/nsn/5961-00-921-649
Inclosure Material:
Glass and metal
Overall Length:
0.800 inches
Overall Diameter:
0.424 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
110.0 regulator voltage
Current Rating Per Characteristic:
23.00 milliamperes repetitive peak forward current
Power Rating Per Characteristic:
10.0 watts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius case
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 1 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0